2SA2222SG

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Bipolar Transistor -50V, -10A, Low VCE(sat) PNP TO-220F-3FS

Applications

· Relay drivers, lamp drivers, motor drivers

Features

· Adoption of MBIT process

- Large current capacity (IC=-10A)
- Low collector-to-emitter saturation voltage (VCE(sat)=-250mV(typ.))
- High-speed switching (tf=22ns(typ.))

Specifications

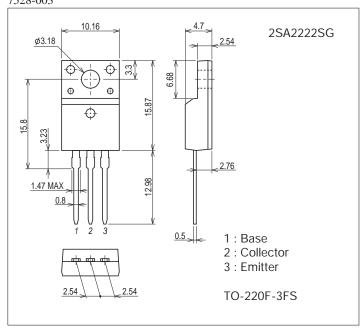
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-50	V
Collector-to-Emitter Voltage	VCEO		-50	V
Emitter-to-Base Voltage	V _{EBO}		-6	V
Collector Current	IC		-10	Α
Collector Current (Pulse)	ICP		-13	Α
Base Current	ΙΒ		-2	Α
Collector Dissipation	PC	Tc=25°C, P _T ≤1s	25	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7528-003



Product & Package Information

• Package : TO-220F-3FS

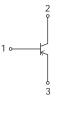
• JEITA, JEDEC : SC-67

• Minimum Packing Quantity: 50 pcs./magazine

Marking

Electrical Connection

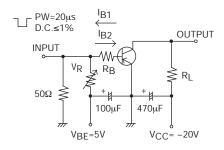




Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Syllibol	Conditions	min	typ	max	Utill	
Collector Cutoff Current	ICBO	V _{CB} =-40V, I _E =0A			-10	μΑ	
Emitter Cutoff Current	IEBO	V _{EB} =-4V, I _C =0A			-10	μΑ	
DC Current Gain	hFE	V _{CE} =-2V, I _C =-270mA	150		450		
Gain-Bandwidth Product	fŢ	V _{CE} =-10V, I _C =-1A		230		MHz	
Output Capacitance	Cob	V _{CB} =-10V, f=1MHz		115		pF	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	IC=-6A, IB=-300mA		-250	-500	mV	
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=-6A, IB=-300mA			-1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =-100μA, I _E =0A	-50			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=-1mA, RBE=∞	-50			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =-100μA, I _C =0A	-6			V	
Turn-On Time	ton			40		ns	
Storage Time	t _{stg}	See specified Test Circuit.		240		ns	
Fall Time	tf			22		ns	

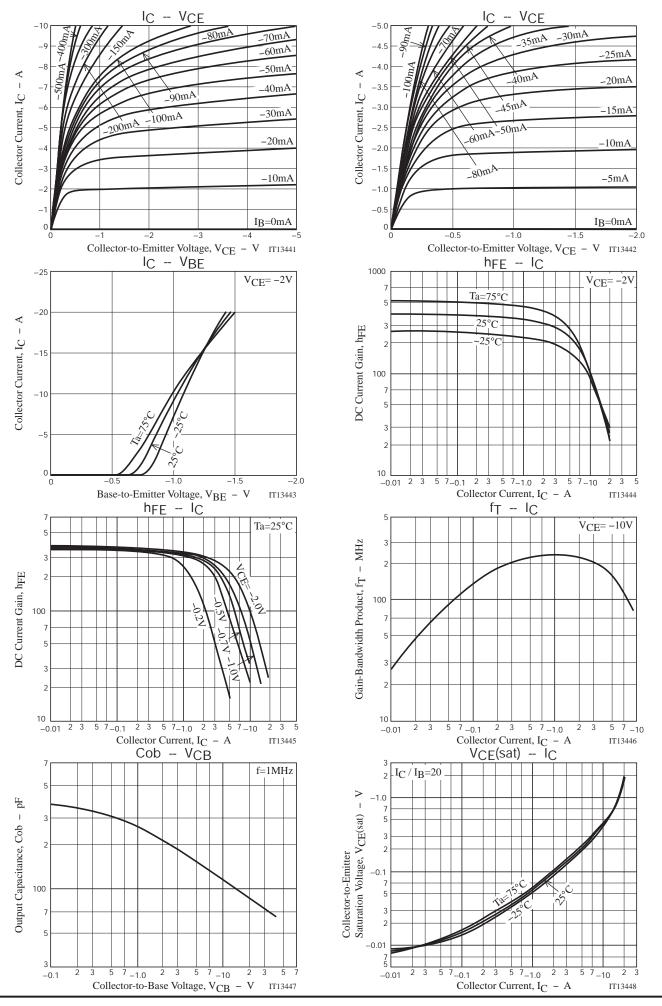
Switching Time Test Circuit

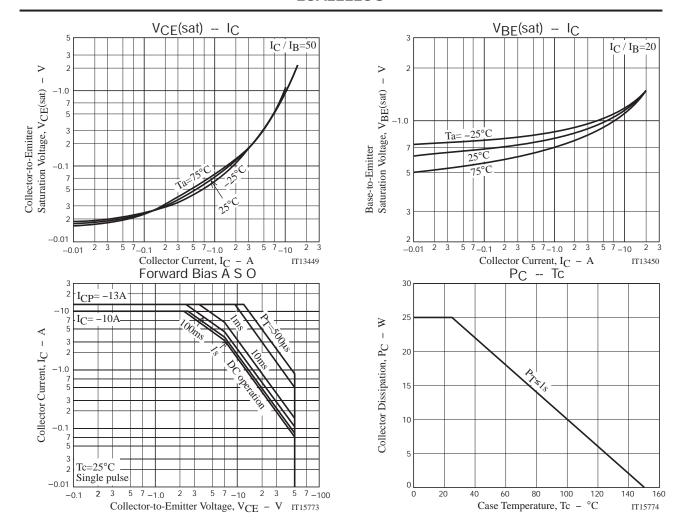


 $I_{C}=20I_{B1}=-20I_{B2}=-5A$

Ordering Information

Device	Package	Shipping	memo
2SA2222SG	TO-220F-3FS	50pcs./magazine	Pb Free



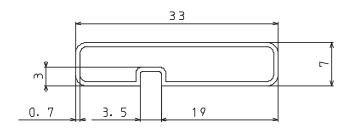


Magazine Specification

2SA2222SG

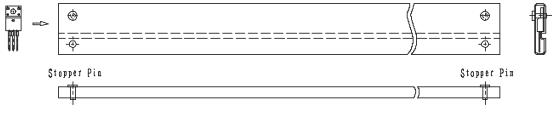
1. Packing Format

Package Name	Magazine Name	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		Maximum Number of devices contained (pcs)			Packing format		
1 4 4 4 6 4 1 (4 4 4 4	Idagas ing Hams	I	Inner box	Outer box	Inner BOX	Outer BOX			
TO-220F-3F\$	TO-220F	50	1, 000	4,000	SPD-0V0001 20 magazines contained Dimensions:mm (external) 568×150×55	SPT-081029 4 inner boxes contained Dimensions:mm (external) 590×225×178			

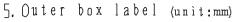


Tolerance=±0, 3mm
Thickness=0, 7±0, 2mm
Length =532, 5±2mm
Material =PVC (Antistatic treatment)

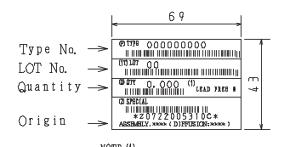
3. Storage method to magazine

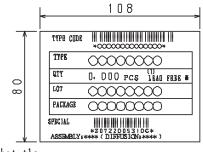


4. Inner box label (unit:mm)



It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



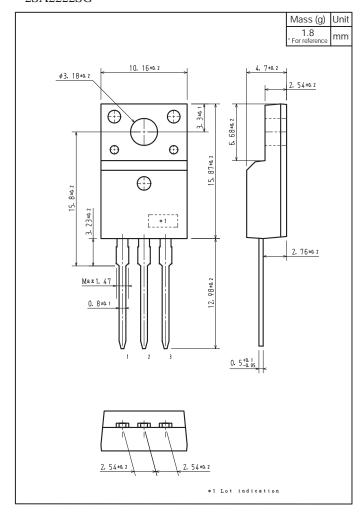


The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Label		JEITA Phase
LEAD FREE	3	JEITA Phase 3A

Outline Drawing

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